Preferred Device

SWITCHMODE™ Power Rectifier

... designed for use in switching power supplies, inverters and as free wheeling diodes, these state-of-the-art devices have the following features:

- Ultrafast 35 Nanosecond Recovery Times
- 150°C Operating Junction Temperature
- Electrically Isolated. No Isolation Hardware Required.
- Epoxy Meets UL94, V_O @ 1/8"
- High Temperature Glass Passivated Junction
- High Voltage Capability to 600 Volts
- Low Leakage Specified @ 150°C Case Temperature

Mechanical Characteristics

- Case: Epoxy, Molded
- Weight: 1.9 grams (approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead Temperature for Soldering Purposes: 260°C Max. for 10 Seconds
- Shipped 50 units per plastic tube
- Marking: UH860

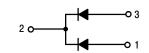
MAXIMUM RATINGS (Per Leg)

| Rating | Symbol | Value | Unit |
|---|--|-------------|------|
| Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage | V _{RRM} V _{RWM} V _R | 600 | V |
| Average Rectified Forward Current (Rated V _R , T _C = 120°C) Total Device | I _{F(AV)} | 4.0 8.0 | Α |
| Peak Repetitive Forward Current (Rated V _R , Square Wave, 20 kHz, T _C = 120°C) | I _{FM} | 16 | A |
| Non–Repetitive Peak Surge Current (Surge Applied at Rated Load Conditions Halfwave, Single Phase, 60 Hz) | I _{FSM} | 100 | А |
| Operating Junction and Storage Temperature Range | T _J , T _{stg} | -65 to +150 | °C |



http://onsemi.com

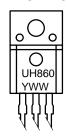
ULTRAFAST RECTIFIER 8.0 AMPERES 600 VOLTS





ISOLATED TO-220 CASE 221D STYLE 4

MARKING DIAGRAM



UH860 = Specific Device Code

Y = Year WW = Work Week

ORDERING INFORMATION

| Device | Package | Shipping |
|------------|---------|---------------|
| MURHF860CT | TO-220 | 50 Units/Rail |

Preferred devices are recommended choices for future use and best overall value.

THERMAL CHARACTERISTICS (Per Leg)

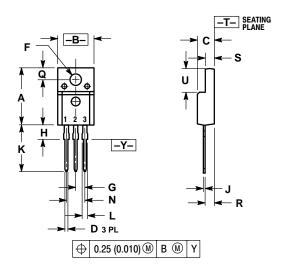
| Characteristic | Symbol | Value | Unit |
|---|-----------------|------------|-------|
| Maximum Thermal Resistance, Junction to Case | $R_{	heta JC}$ | 4.1 | °C/W |
| ELECTRICAL CHARACTERISTICS (Per Leg) | | | |
| Maximum Instantaneous Forward Voltage (Note 1) ($i_F = 4.0 \text{ Amps}$, $T_C = 150^{\circ}\text{C}$) ($i_F = 4.0 \text{ Amps}$, $T_C = 25^{\circ}\text{C}$) | VF | 2.5 2.8 | Volts |
| Maximum Instantaneous Reverse Current (Note 1) (Rated dc Voltage, T _C = 150°C) (Rated dc Voltage, T _C = 25°C) | i _R | 500 10 | μА |
| Maximum Reverse Recovery Time (I _F = 1.0 Amp, di/dt = 50 Amps/μs) | t _{rr} | 35 | ns |

^{1.} Pulse Test: Pulse Width = 300 μs, Duty Cycle ≤ 2.0%

PACKAGE DIMENSIONS

TO-220 FULLPAK TRANSISTOR

CASE 221D-03 **ISSUE G**



- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH
 3. 221D-01 THRU 221D-02 OBSOLETE, NEW STANDARD 221D-03.

| | INCHES | | MILLIMETERS | |
|-----|-----------|-------|-------------|-------|
| DIM | MIN | MAX | MIN | MAX |
| Α | 0.625 | 0.635 | 15.88 | 16.12 |
| В | 0.408 | 0.418 | 10.37 | 10.63 |
| С | 0.180 | 0.190 | 4.57 | 4.83 |
| D | 0.026 | 0.031 | 0.65 | 0.78 |
| F | 0.116 | 0.119 | 2.95 | 3.02 |
| G | 0.100 BSC | | 2.54 BSC | |
| Н | 0.125 | 0.135 | 3.18 | 3.43 |
| J | 0.018 | 0.025 | 0.45 | 0.63 |
| K | 0.530 | 0.540 | 13.47 | 13.73 |
| L | 0.048 | 0.053 | 1.23 | 1.36 |
| N | 0.200 | BSC | 5.08 BSC | |
| Q | 0.124 | 0.128 | 3.15 | 3.25 |
| R | 0.099 | 0.103 | 2.51 | 2.62 |
| S | 0.101 | 0.113 | 2.57 | 2.87 |
| U | 0.238 | 0.258 | 6.06 | 6.56 |

- STYLE 4:
 PIN 1. CATHODE
 2. ANODE
 3. CATHODE

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